## NSN 5961-00-058-6280

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View Online at https://aerobasegroup.com/nsn/5961-00-058-6280

view Offiline at https://aerobasegroup.com/nish/5561-505-0200
Inclosure Material:
Metal
Overall Length:
0.520 inches
Overall Height:
0.520 inches
Overall Diameter:
1.250 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Internal Junction Configuration:
Npn
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage, dc with specified circuit between base and emitter
and 50.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open
Current Rating Per Characteristic:
6.00 amperes source cutoff current megahertz and 10.00 amperes collector current, dc
Power Rating Per Characteristic:
150.0 watts collector power dissipation
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 pin and 1 threaded stud

NI/o

Shelf Life:

**Specification Data:** 

81349-mil-s-19500/248 government specification

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Demilitarization:

No

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